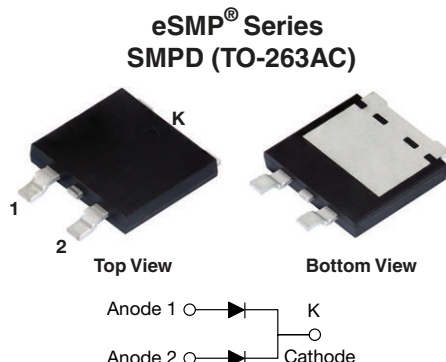


Hyperfast Rectifier, 2 x 15 A FRED Pt®



FEATURES

- Hyperfast recovery time, reduced Q_{rr} , and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_R	600 V
V_F at I_F ($T_J = 150$ °C)	1.22 V
t_{rr}	30 ns
T_J max.	175 °C
Package	SMPD (TO-263AC)
Circuit configuration	Common cathode

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating
Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$ ⁽¹⁾	$T_C = 130$ °C	30	A
			15	
Non-repetitive peak surge current, per diode	I_{FSM}	$T_J = 25$ °C, 10 ms sine pulse	160	

ELECTRICAL SPECIFICATIONS ($T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100$ μ A	600	-	-	V
Forward voltage, per diode	V_F	$I_F = 15$ A	-	1.63	2.15	
		$I_F = 15$ A, $T_J = 150$ °C	-	1.22	1.65	
Reverse leakage current, per diode	I_R	$V_R = V_R$ rated	-	-	20	μ A
		$T_J = 150$ °C, $V_R = V_R$ rated	-	-	500	
Junction capacitance, per diode	C_T	$V_R = 600$ V	-	16	-	pF

Note

⁽¹⁾ Mounted on infinite heatsink

**DYNAMIC RECOVERY CHARACTERISTICS** ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time per diode	t_{rr}	$I_F = 1\text{ A}$, $dl_F/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	30	-	ns
		$I_F = 0.5\text{ A}$, $I_R = 1\text{ A}$, $I_{rr} = 0.25\text{ A}$	-	-	30	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	41	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	92	-	
Peak recovery current per diode	I_{RRM}	$T_J = 25\text{ }^{\circ}\text{C}$	-	7	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	13	-	
Reverse recovery charge per diode	Q_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	150	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	590	-	

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		-55	-	+175	$^{\circ}\text{C}$
Thermal resistance, junction to mount, per diode	R_{thJM}		-	1.2	1.7	$^{\circ}\text{C}/\text{W}$
Approximate weight			0.55			g
			0.02			oz.
Marking device		Case style SMPD (TO-263AC)	30CDH06			

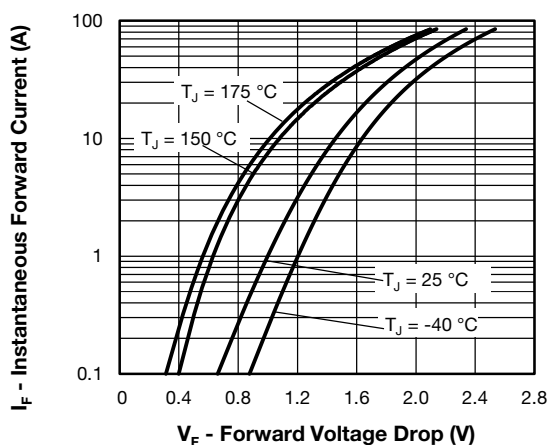


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Diode

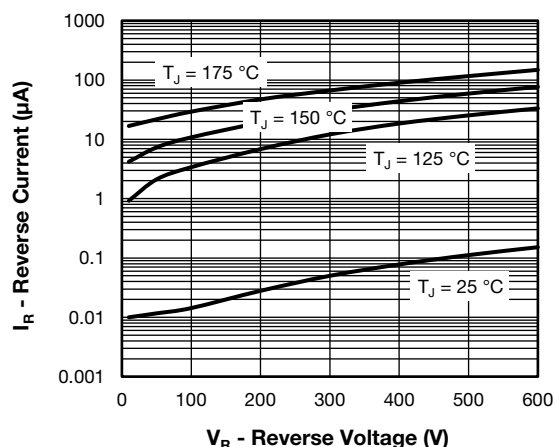


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Diode

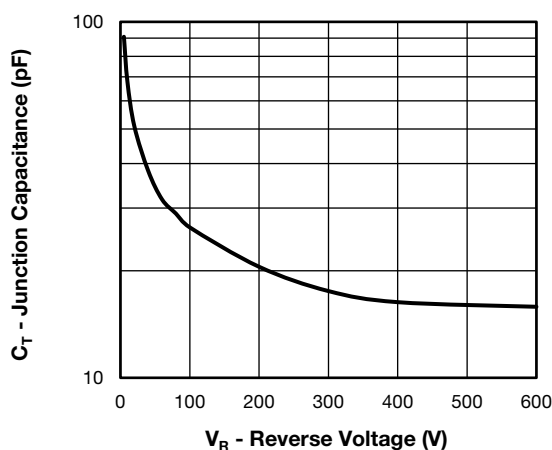


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Diode

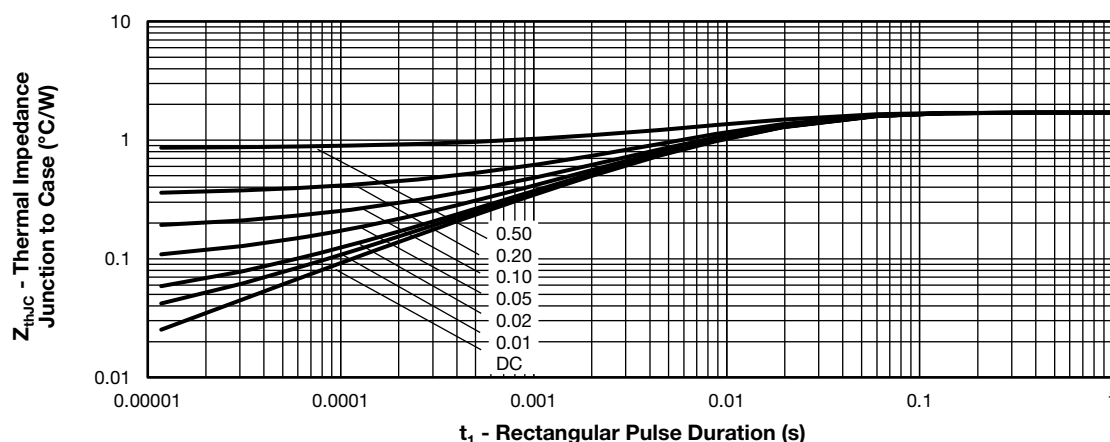


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics, Per Diode

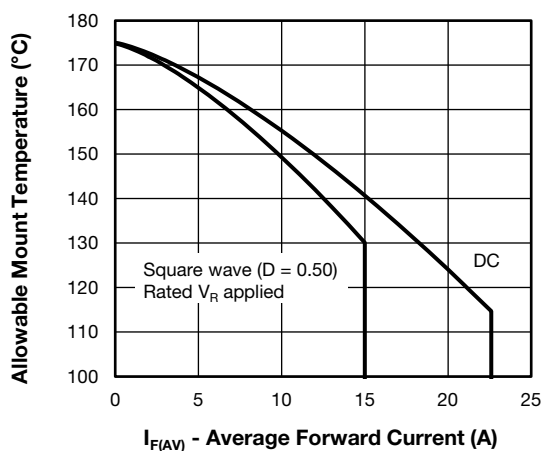


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current, Per Diode

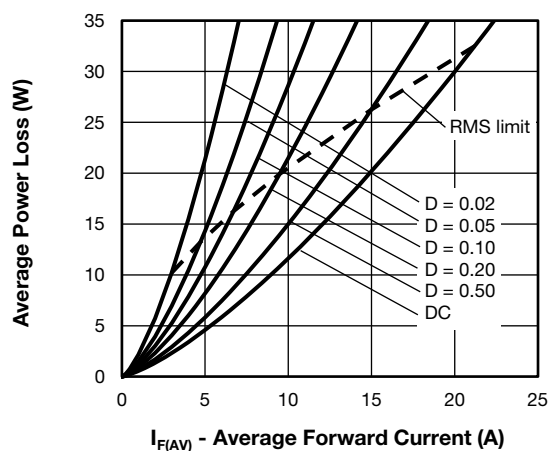


Fig. 6 - Forward Power Loss Characteristics, Per Diode

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 5);
 P_{dREV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

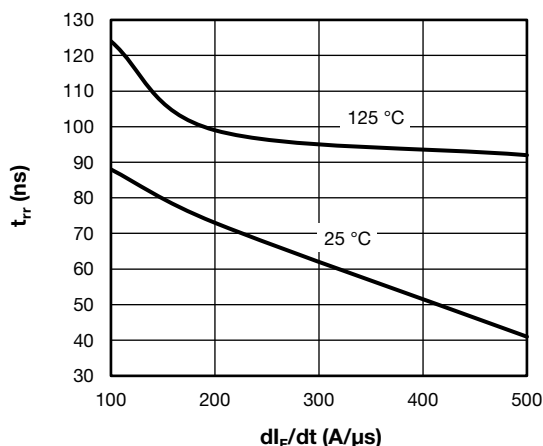
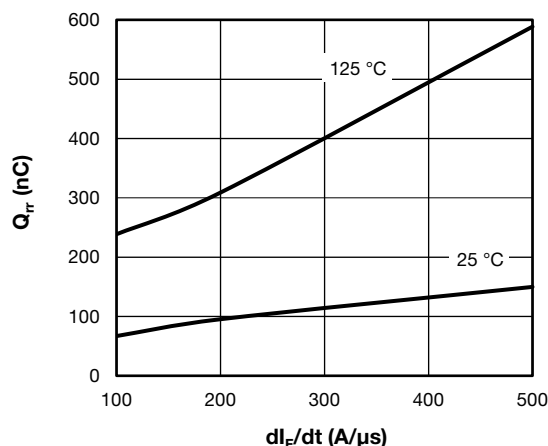
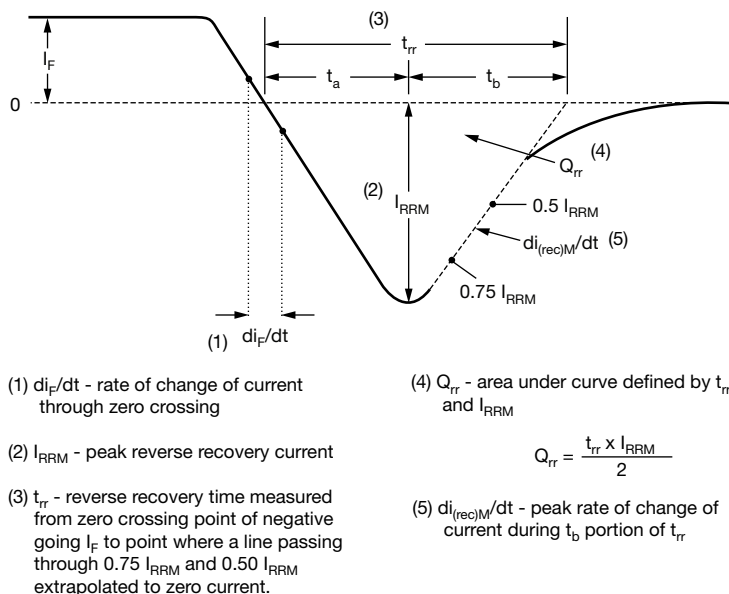

Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt , Per Diode

Fig. 8 - Typical Stored Charge vs. di_F/dt , Per Diode


Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code	VS-	30	C	D	H	06	-M3
	1	2	3	4	5	6	7
	1	- Vishay Semiconductors product					
	2	- Current rating (30 A)					
	3	- Circuit configuration: C = common cathode					
	4	- D = SMPD package					
	5	- Process type, H = hyperfast recovery					
	6	- Voltage code (06 = 600 V)					
	7	- -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free					

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-30CDH06-M3/I	2000	2000	13" diameter plastic tape and reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95604
Part marking information	www.vishay.com/doc?95566
Packaging information	www.vishay.com/doc?88869
SPICE model	www.vishay.com/doc?96776

TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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